

Technical Data Data Sheet N1735, Rev. A **Green Products**

DF01 THRU DF07 SINGLE-PHASE GLASS PASSIVATED SILICON BRIDGE RECTIFIER

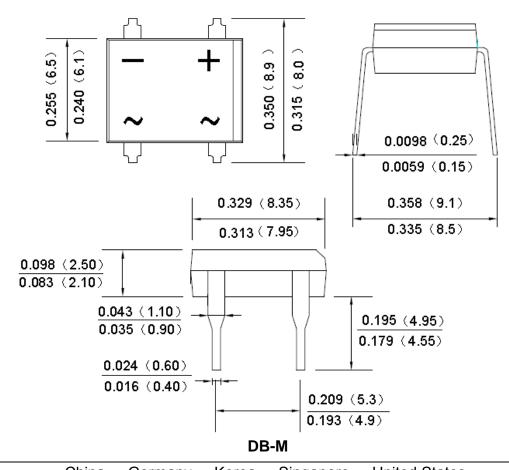
Features:

- Glass passivated die construction
- Low forward voltage drop
- High current capability
- High surge current capability
- Plastic material-UL flammability 94V-0

Mechanical Data:

- Case: DB-M, molded plastic
- Terminals: plated leads solderable per MIL-STD-202, Method 208
- Polarity: as marked on case
- Mounting position: Any
- Marking: type number
- Lead Free: For RoHS / Lead Free Version,

Mechanical Dimensions: In Inches/ mm



- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •





Technical Data Data Sheet N1735, Rev. A Green Products

Ordering Information:

Device	Package	Shipping	
DF01-DF07	DB-M	50pcs / tube	
	(Pb-Free)	50pcs / tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings and Electrical Characteristics $@T_A=25^{\circ}C$ unless otherwise specified Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Type Number	Symbol	DF01	DF02	DF03	DF04	DF05	DF06	DF07	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Average Forward Output Current (Note 1) @ T _A = 40°C	Io	1.0							А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	50							Α
Forward Voltage Drop per Bridge Element @IF=1.0A	V _F	1.1							٧
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 125°C	I _R	I _R 5 500						μA	
Typical Junction Capacitance per leg (Note 2)	CJ	25						pF	
Typical Thermal Resistance per leg	$R_{\theta JA}$								°C/W
- ypican inclinant issues per log	$R_{\theta JL}$	15							
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55+150					°C		

Note: 1. Mounted on glass epoxy PC board with 1.3mm² solder pad.

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^{2.} Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.



Technical Data Data Sheet N1735, Rev. A Green Products

Fig. 1 Output Current Derating Curve

(**)

1.0

0.8

0.4

0.4

0.2

Resistive or Inductive Load

0 40 80 120 160

T_A, AMBIENT TEMPERATURE (°C)

Fig. 3 Maximum Peak Forward Surge Current (per leg)

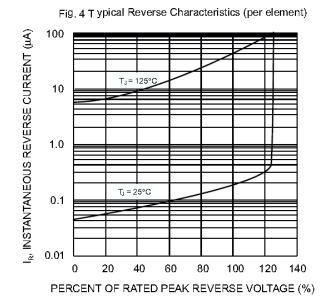
AU

AU

TA = 25°C
Single Half Sine-Wave
Pulse Width =8.3ms
(JEDEC Method)

1.0

NUMBER OF CYCLES AT 60 Hz



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